

NJM1458

The NJM1458 is a monolithic pair of Internally Compensated High Performance Amplifiers, constructed using the New JRC Planar epitaxial process. They are intended for a wide range of analog applications where board space or weight are important. High common mode voltage range and absence of "latch-up" make the NJM1458 ideal for use as voltage followers. The high gain and wide range of operating voltage provides superior performance in integrator, summing amplifier and general feedback applications.

The NJM1458 is short-circuit protected and require no external components for frequency compensation. The internal 6 dB/octabe roll-off insures stability in closed loop applications. For single amplifier performance, see the NJM741 data sheet.

Package Outline

Absolute Maximum Ratings (Ta=25°C)

| Supply Voltage | V^+/V^- | ±18V | |
|-----------------------------|-------------------------|------------|--|
| Input Voltage (note) | $\mathbf{V_1}$ | ±15V | |
| Differential Input Voltage | V_{ID} | ±30V | |
| Power Dissipation | P _D (D-Type) | 500mW | |
| | (M-Type) | 300mW | |
| Operating Temperature Range | T_{opr} | -20~+75°C | |
| Storage Temperature Range | T_{stg} | -40~+125°C | |

(note) For supply voltages less than ±15V, the absolute maximum





NJM1458M

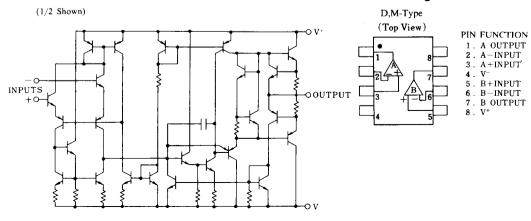
input voltage is equal to the supply voltage.

Electrical Characteristics ($Ta=25^{\circ}C$, $V^{+}/V^{-}=\pm15V$)

| Parameter | Symbol | Test Condition | Min. | Тур. | Max. | Unit |
|---------------------------------|------------------|--------------------------------------|------|------|------|------|
| Input Offset Voltage | Vio | $R_S \leq 10 k\Omega$ | _ | 2.0 | 6.0 | mV |
| Input Offset Current | I _{IO} | | - | 30 | 200 | nΑ |
| Input Bias Current | IB | | | 60 | 500 | nA |
| Input Resistance | R _{IN} | | 0.3 | 1.0 | | MΩ |
| Large-signal Voltage Gain | A_{V} | $R_L \ge 2k\Omega$, $V_0 = \pm 10V$ | 86 | 106 | _ | dB |
| Maximum Output Voltage Swing I | V _{OM1} | R _L ≥10kΩ | ±12 | ±14 | _ | V |
| Maximum Output Voltage Swing II | V _{OM2} | $R_L \ge 2k\Omega$ | ±10 | ±13 | _ | V |
| Input Common Mode Voltage Range | V _{ICM} | | ±12 | ±13 | | v |
| Common Mode Rejection Ratio | CMR | R _S ≦10kΩ | 70 | 90 | l — | dB |
| Supply Voltage Rejection Ratio | SVR | $R_S \leq 10k\Omega$ | 76.5 | 90 | _ | dB |
| Supply Current | I _{cc} | | _ | 3.3 | 5.7 | mA |
| Slew Rate | SR | $R_L \ge 2k\Omega$, $A_V = 1$ | _ | 0.5 | | V/µs |
| Channel Separation Ratio | CS | f=1kHz | _ | 98 | _ | dB |

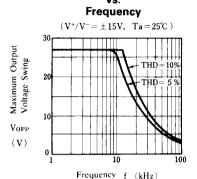
Equivalent Circuit

■ Connection Diagram

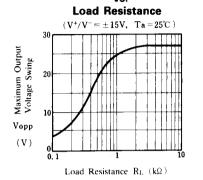


■ Typical Characteristics

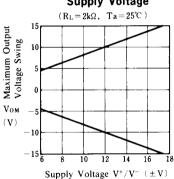
Maximum Output Voltage Swing vs.



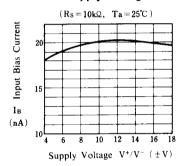
Maximum Output Voltage Swing vs.



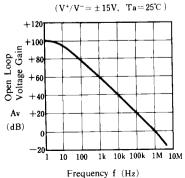
Maximum Output Voltae Swing vs. Supply Voltage



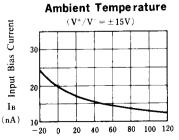
Input Bias Current vs. Supply Voltage



Open Loop Frequency Response



Input Bias Current vs.



Ambient Temperature Ta (*C)

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